

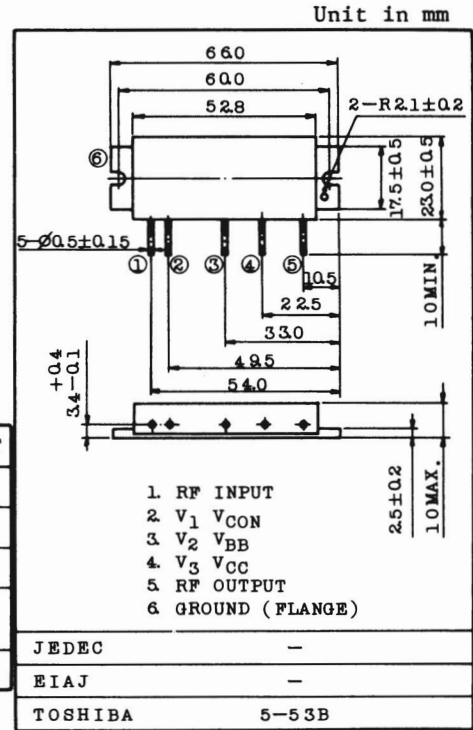
UHF POWER AMPLIFIER MODULE (HAM SSB/FM)

FEATURES:

- . Output Power :  $P_o \geq 17W$
- . Minimum Gain :  $G_p = 19.2dB$
- . Efficiency :  $\eta_T \geq 35\%$
- .  $50\Omega$  Input/Output Impedance
- . Guaranteed Stability

MAXIMUM RATINGS ( $T_c = 25^\circ C$ )

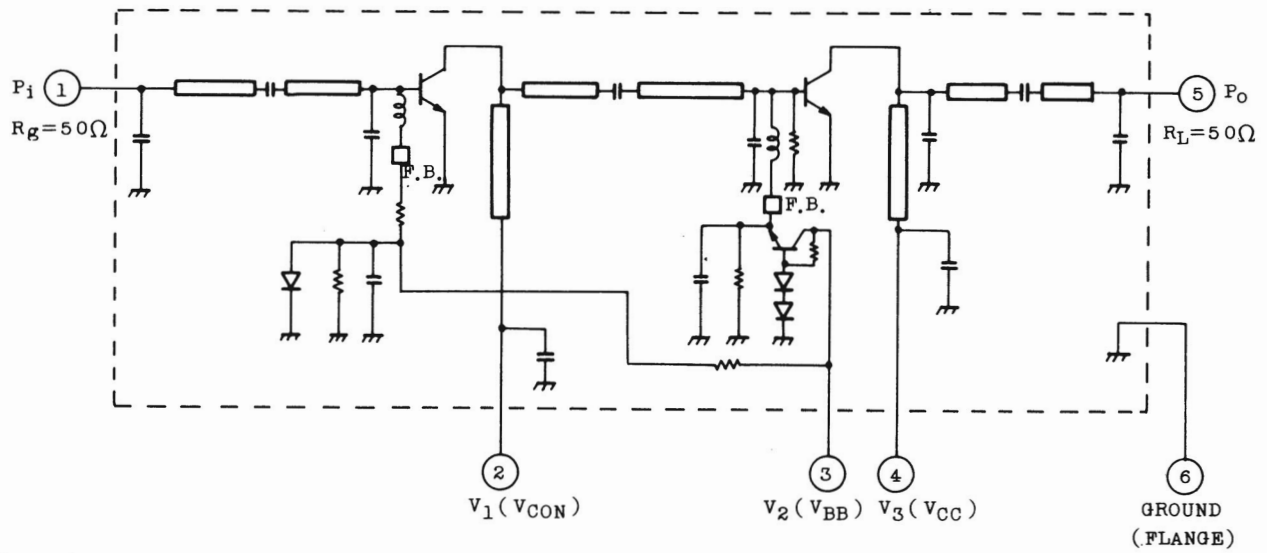
CHARACTERISTIC	SYMBOL	RATING	UNIT
DC Supply Voltage	VCC	16	V
DC Supply Voltage	VCON	16	V
RF Input Power	Pi	300	mW
Operating Case Temperature Range	Tc(OP)	-30 ~ 100	°C
Storage Temperature Range	Tstg	-40 ~ 110	°C



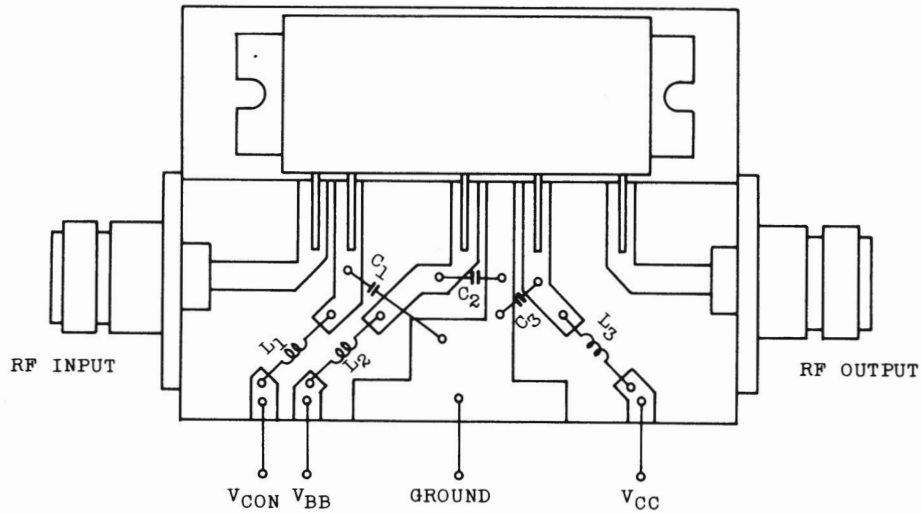
CHARACTERISTICS ( $T_c = 25^\circ C$ )

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Frequency Range	f <sub>range</sub>	-	430	-	450	MHz
Output Power	P <sub>o</sub>	P <sub>i</sub> =200mW VCC=12.5V, VCON=12.5V Z <sub>g</sub> =Z <sub>l</sub> =50Ω	17	20	-	W
Power Gain	G <sub>p</sub>		19.2	20	-	dB
Total Efficiency	η <sub>T</sub>		35	45	-	%
Input VSWR	VSWR <sub>in</sub>		-	1.5	2	-
Harmonics	HRM		-	-30	-25	dB
Load Mismatch	-	VCC=15V, VCON=12.5V P <sub>o</sub> =20W VSWR load 20:1 all phase	No Degradation			-
Stability	-	VCC=12.5V, P <sub>i</sub> =200mW VCON=0 ~ 12.5V VSWR Load 3:1 all phase	All spurious output than 60dB below desired signal			-
Intermodulation Distortion Ratio	IMD	f <sub>1</sub> =440.000MHz, f <sub>2</sub> =440.002MHz VCC=VCON=12.5V, VBB=9V P <sub>o</sub> =13W <sub>PEP</sub>	-	-32	-	dB

SCHEMATIC



TEST MOUNT



$C_1, C_2, C_3 : 1500pF, 10\mu F$

$L_1, L_2, L_3 : \varnothing 0.8 \text{ COPPER WIRE, } 8T, 5ID$

